

MOSFETs Silicon N-Channel MOS ( $\pi$ -MOSVII)

# TK16A55D

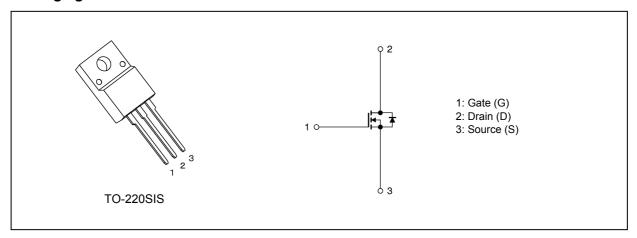
#### 1. Applications

• Switching Voltage Regulators

#### 2. Features

- (1) Low drain-source on-resistance:  $R_{DS(ON)} = 0.28 \Omega$  (typ.)
- (2) High forward transfer admittance:  $|Y_{fs}| = 9.0 \text{ S (typ.)}$
- (3) Low leakage current:  $I_{DSS}$  = 10  $\mu A$  (max) ( $V_{DS}$  = 550 V)
- (4) Enhancement mode:  $V_{th} = 2.0$  to 4.0 V ( $V_{DS} = 10$  V,  $I_D = 1$  mA)

#### 3. Packaging and Internal Circuit



## 4. Absolute Maximum Ratings (Note) (T<sub>a</sub> = 25°C unless otherwise specified)

Characteristics			Rating	Unit
Drain-source voltage		$V_{DSS}$	550	V
Gate-source voltage		V <sub>GSS</sub>	±30	
Drain current (DC)	(Note 1)	I <sub>D</sub>	16	Α
Drain current (pulsed)	(Note 1)	I <sub>DP</sub>	64	
Power dissipation	(T <sub>c</sub> = 25°C)	P <sub>D</sub>	50	W
Single-pulse avalanche energy	(Note 2)	E <sub>AS</sub>	528	mJ
Avalanche current	(Note 3)	I <sub>AR</sub>	16	Α
Repetitive avalanche energy	(Note 3)	E <sub>AR</sub>	5.0	mJ
Reverse drain current (DC)	(Note 1)	I <sub>DR</sub>	16	Α
Reverse drain current (pulsed)	(Note 1)	I <sub>DRP</sub>	64	
Channel temperature		T <sub>ch</sub>	150	°C
Storage temperature		T <sub>stg</sub>	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production



### 5. Thermal Characteristics

Characteristics		Max	Unit
Channel-to-case thermal resistance	R <sub>th(ch-c)</sub>	2.5	°C/W
Channel-to-ambient thermal resistance	R <sub>th(ch-a)</sub>	62.5	

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2:  $V_{DD}$  = 90 V,  $T_{ch}$  = 25°C (initial), L = 3.56 mH,  $R_{G}$  = 25  $\Omega,$   $I_{AR}$  = 16 A

Note 3: Repetitive rating; pulse width limited by maximum channel temperature

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.



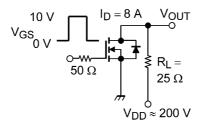
### 6. Electrical Characteristics

### 6.1. Static Characteristics (T<sub>a</sub> = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I <sub>GSS</sub>	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$	_		±1	μА
Drain cut-off current	I <sub>DSS</sub>	V <sub>DS</sub> = 550 V, V <sub>GS</sub> = 0 V	_	_	10	
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	550	_	_	٧
Gate threshold voltage	$V_{th}$	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	2.0		4.0	
Drain-source on-resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 8 A	_	0.28	0.33	Ω
Forward transfer admittance	Y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 8 A	2.4	9.0	_	S

## 6.2. Dynamic Characteristics (T<sub>a</sub> = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V, f = 1 MHz	_	2600	_	pF
Reverse transfer capacitance	C <sub>rss</sub>		_	11	_	
Output capacitance	C <sub>oss</sub>		_	280	_	
Switching time (rise time)	t <sub>r</sub>	See Figure 6.2.1	_	50	_	ns
Switching time (turn-on time)	t <sub>on</sub>		_	100	_	
Switching time (fall time)	t <sub>f</sub>		_	25	_	
Switching time (turn-off time)	t <sub>off</sub>		_	150		



Duty  $\leq$  1%,  $t_W=10~\mu s$ 

Fig. 6.2.1 Switching Time Test Circuit

## 6.3. Gate Charge Characteristics ( $T_a = 25$ °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	$Q_g$	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 16 \text{ A}$	_	45	_	nC
Gate-source charge	$Q_{gs}$		_	28	_	
Gate-drain charge	$Q_{gd}$		_	17	_	

### 6.4. Source-Drain Characteristics (T<sub>a</sub> = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Diode forward voltage	$V_{DSF}$	I <sub>DR</sub> = 16 A, V <sub>GS</sub> = 0 V	_		-1.7	V
Reverse recovery time		I <sub>DR</sub> = 16 A, V <sub>GS</sub> = 0 V	_	1700	_	ns
Reverse recovery charge	$Q_{rr}$	-dI <sub>DR</sub> /dt = 100 A/μs	_	26	_	μС



## 7. Marking (Note)

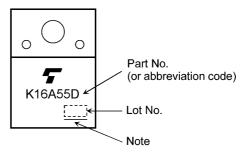


Fig. 7.1 Marking

Note: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

### 8. Characteristics Curves (Note)

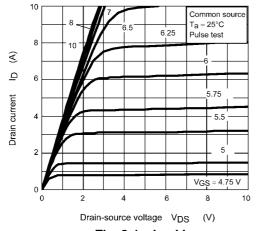


Fig. 8.1 I<sub>D</sub> - V<sub>DS</sub>

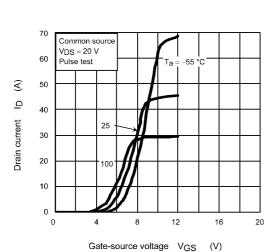
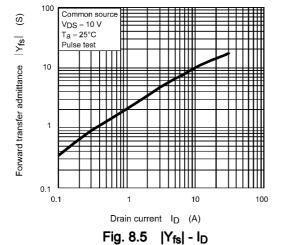


Fig. 8.3 I<sub>D</sub> - V<sub>GS</sub>



20 Common source T<sub>a</sub> = 25°C Pulse test 16  $\widehat{\mathbf{A}}$ 6.75 0 12 6.5 Drain current 6 5.5 = 5 V 0 12 0 8 16 Drain-source voltage V<sub>DS</sub> (V)

Fig. 8.2 I<sub>D</sub> - V<sub>DS</sub>

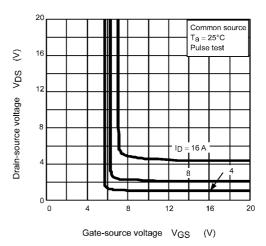


Fig. 8.4 V<sub>DS</sub> - V<sub>GS</sub>

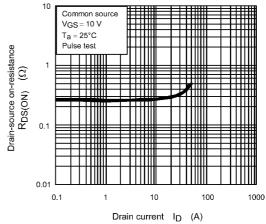


Fig. 8.6 R<sub>DS(ON)</sub> - I<sub>D</sub>

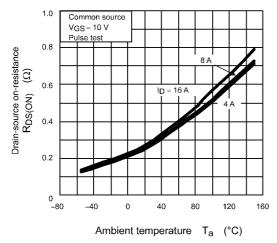
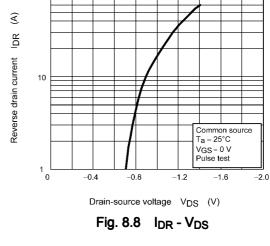


Fig. 8.7 R<sub>DS(ON)</sub> - T<sub>a</sub>



100

5 | | | | | | | Comm

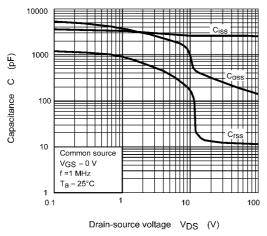


Fig. 8.9 C - V<sub>DS</sub>

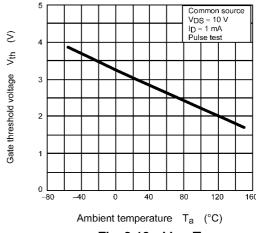


Fig. 8.10  $V_{th}$  -  $T_a$ 

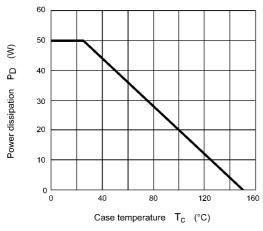


Fig. 8.11 P<sub>D</sub> - T<sub>c</sub> (Guaranteed Maximum)

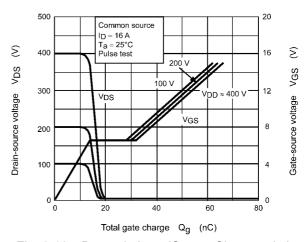


Fig. 8.12 Dynamic Input/Output Characteristics

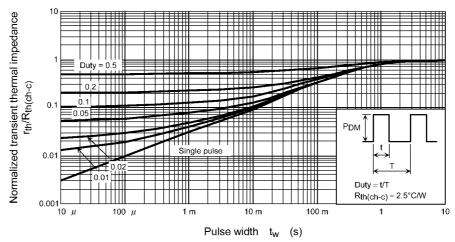


Fig. 8.13  $r_{th}/R_{th(ch-c)} - t_w$  (Guaranteed Maximum)

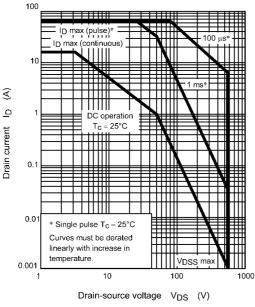


Fig. 8.14 Safe Operating Area (Guaranteed Maximum)

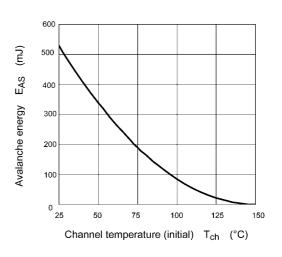


Fig. 8.15 E<sub>AS</sub> - T<sub>ch</sub> (Guaranteed Maximum)

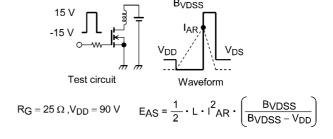


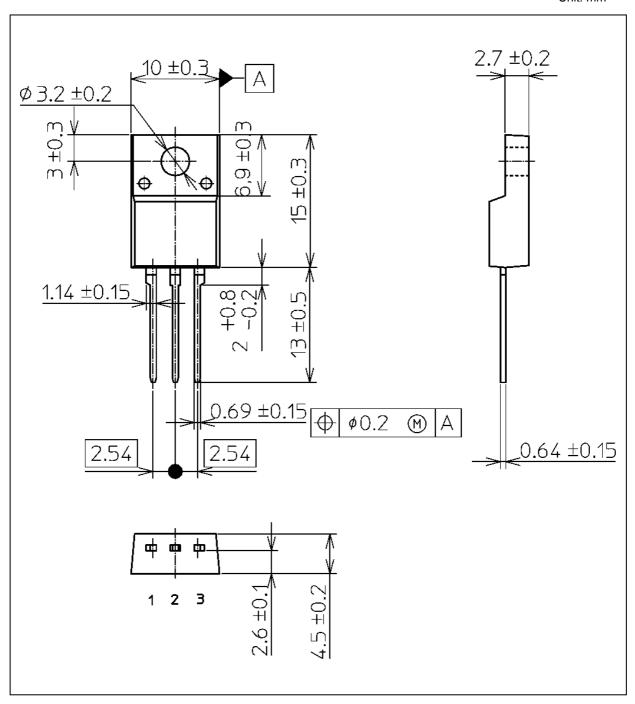
Fig. 8.16 Test Circuit/Waveform

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



### **Package Dimensions**

Unit: mm



Weight: 1.7 g (typ.)

	Package Name(s)
JEITA: SC-67	
TOSHIBA: 2-10U1S	
Nickname: TO-220SIS	



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